

L Number	Hits	Search Text	DB	Time stamp
67	3	(US-5708288-\$ or US-5610790-\$ or US-5124877-\$).did.	USPAT	2004/04/15 10:45
68	40	(esd or eos) with zener and (zener) with (single or one or singular or diode!) with (plural or plurality or series or serial or multiple)	USPAT	2004/04/15 10:46
69	51	(esd or eos) with zener and (zener) with (single or one or singular or diode!) with (plural or plurality or series or serial or multiple)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/04/15 10:52
70	12	(esd or eos) with zener and zener near3 (string or plurality or plural)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/04/15 10:52
71	13	(esd or eos) with zener and zener near3 (string or plurality or plural or chain)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/04/15 10:52
-	2	5708288.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/08 15:51
-	17	(soi or silicon adj on adj insulator or recrystalliz\$ or polycrystal\$) same (zener) same (eos or esd or electrostatic or electro-static or electrical near2 discharge or electricity near2 discharge or static near2 electricity or electrical near2 overstress)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/06 16:08
-	12	("4037140" "4282556" "4794437" "4989057" "4996626" "5041889" "5124877" "5210442" "5223444" "5264723" "5283449" "5311391").PN.	USPAT	2004/04/06 15:57
-	21	(soi or silicon adj on adj insulator or recrystalliz\$ or polycrystal\$ or buried adj oxide or buried adj insulator or box) same (zener) same (eos or esd or electrostatic or electro-static or electrical near2 discharge or electricity near2 discharge or static near2 electricity or electrical near2 overstress or discharge near2 protection)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/06 16:10
-	24	(soi or silicon adj on adj insulator or recrystalliz\$ or polycrystal\$ or buried adj oxide or buried adj insulator or box or sapphire near2 substrate or insulating near2 substrate) same (zener) same (eos or esd or electrostatic or electro-static or electrical near2 discharge or electricity near2 discharge or static near2 electricity or electrical near2 overstress or discharge near2 protection)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/08 15:12
-	3	3728591.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/06 16:11
-	24	(soi or silicon adj on adj insulator or recrystalliz\$ or polycrystal\$ or buried adj oxide or buried adj insulator or box or sapphire near2 substrate or insulating near2 substrate or tft or thin adj film adj transistor) same (zener) same (eos or esd or electrostatic or electro-static or electrical near2 discharge or electricity near2 discharge or static near2 electricity or electrical near2 overstress or discharge near2 protection)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/08 15:13

-	526	(soi or silicon adj on adj insulator or recrystalliz\$ or polycrystal\$ or buried adj oxide or buried adj insulator or box or sapphire near2 substrate or insulating near2 substrate or tft or thin adj film adj transistor) same (zener)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/08 15:14
-	358	(soi or silicon adj on adj insulator or buried adj oxide or buried adj insulator or box or sapphire near2 substrate or insulating near2 substrate or tft or thin adj film adj transistor) same (zener)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/08 16:00
-	4	5124877.URPN.	USPAT	2004/04/08 15:31
-	8	("4423431" "4989057" "5172208" . "5240865" "5369041" "5399507" "5440153" "5502317").PN.	USPAT	2004/04/08 15:47
-	6	5708288.URPN.	USPAT	2004/04/08 15:49
-	2	5726844.pn.	USPAT;	2004/04/08 15:51
-	81	(soi or silicon adj on adj insulator or buried adj oxide or buried adj insulator or sapphire near2 substrate or insulating near2 substrate or tft or thin adj film adj transistor) same (zener)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/08 16:01
-	5	("5321293" "5608340" "5844272" "5880620" "6274908").PN.	USPAT	2004/04/08 16:04
-	39	5610790.URPN.	USPAT	2004/04/08 16:16
-	12	("4037140" "4282556" "4794437" "4989057" "4996626" "5041889" "5124877" "5210442" "5223444" "5264723" "5283449" "5311391").PN.	USPAT	2004/04/08 16:27